

### **General Description**

The MAX4741/MAX4742/MAX4743 are low on-resistance, low-voltage, dual single-pole/single-throw (SPST) analog switches that operate from a single +1.6V to +3.6V supply. These devices have fast switching speeds (ton = 24ns, toff = 16ns max), handle Rail-to-Rail® analog signals, and consume less than 1µW of quiescent power. The MAX4743 has break-beforemake switching.

When powered from a +3V supply, the MAX4741/ MAX4742/MAX4743 feature low  $0.8\Omega$  (max) on-resistance (R<sub>ON</sub>), with  $0.08\Omega$  (max) R<sub>ON</sub> matching and  $0.18\Omega$  R<sub>ON</sub> flatness. The digital logic input is 1.8V CMOS compatible when using a single +3V supply.

The MAX4741 has two normally open (NO) switches, the MAX4742 has two normally closed (NC) switches. and the MAX4743 has one NO switch and one NC switch. The MAX4741/MAX4742/MAX4743 are available in 8-pin SOT23 and 8-pin µMAX packages.

### **Applications**

**Power Routing** 

**Battery Powered Systems** 

Audio and Video Signal Routing

Low-Voltage Data-Acquisition Systems

Communications Circuits

**PCMCIA Cards** 

Cellular Phones

Modems

Hard Drives

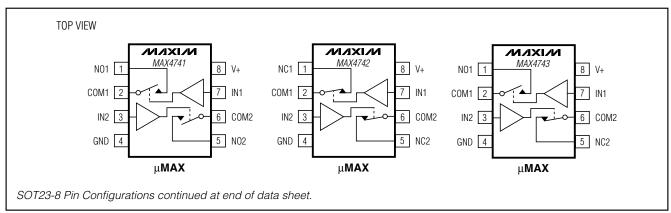
### **Features**

- ♦ Low Ron:
  - $0.8\Omega$  max (+3V Supply) 2.5 $\Omega$  max (+1.8V Supply)
- ♦ 0.18Ω max Ron Flatness (+3V Supply)
- ♦ +1.6V to +3.6V Single-Supply Operation
- ♦ Available in SOT23 and µMAX Packages
- ♦ High-Current Handling Capacity (150mA continuous)
- ♦ 1.8V CMOS Logic Compatible (+3V Supply)
- ♦ Fast Switching: toN = 24ns, toFF = 16ns

### **Ordering Information**

PART	TEMP. RANGE	TEMP. RANGE PIN- PACKAGE	
MAX4741EKA	-40°C to +85°C	8 SOT23-8	AAIY
MAX4741EUA	-40°C to +85°C	8 μΜΑΧ	
MAX4742EKA	-40°C to +85°C	8 SOT23-8	AAIZ
MAX4742EUA	-40°C to +85°C	8 μΜΑΧ	
<b>MAX4743</b> EKA	-40°C to +85°C	8 SOT23-8	AAJA
MAX4743EUA	-40°C to +85°C	8 μΜΑΧ	

### Pin Configurations



Rail-to-Rail is a registered trademark of Nippon Motorola, Inc.

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Maxim Integrated Products 1

### **ABSOLUTE MAXIMUM RATINGS**

٧	oltages Referenced to GND	
V	+, IN	-0.3V to +4V
	COM_, NO_, NC_ (Note 1)0.3V to	
C	Continuous Current COM_, NO_, NC	±150mA
Ρ	eak Current COM_, NO_, NC_	
	(pulsed at 1ms 10% duty cycle)	±300mA
С	Continuous Power Dissipation (TA = +70°C)	
	8-Pin SOT23 (derate 7.52mW/°C above +70°C)	602mW
	8-Pin µMAX (derate 4.5mW/°C above +70°C)	362mW

Operating Temperature Range	40°C to +85°C
Maximum Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

**Note 1:** Signals on COM\_, NO\_, or NC\_ exceeding V+ or GND are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ELECTRICAL CHARACTERISTICS—Single +3V Supply**

 $(V+=+2.7V \text{ to } +3.6V, V_{IH}=+1.4V, V_{IL}=+0.5V, T_A=T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise specified. Typical values are at } V+=+3.0V, T_A=+25^{\circ}C.)$  (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS	
ANALOG SWITCH								
Analog Signal Range	V <sub>COM</sub> , V <sub>NO</sub> , V <sub>NC</sub>			0		V+	V	
On-Resistance	Pov	V+ = 2.7V,	+25°C		0.5	0.8		
On-nesistance	Ron	I <sub>COM</sub> _ = 100mA, V <sub>NO</sub> _ or V <sub>NC</sub> _ = 1.5V	T <sub>MIN</sub> to T <sub>MAX</sub>			0.9	Ω	
On-Resistance Match	A Post	V+ = 2.7V,	+25°C		0.05	0.08	Ω	
Between Channels (Note 4)	ΔRon	ICOM_ = 100mA, V <sub>NO_</sub> or V <sub>NC_</sub> = 1.5V	T <sub>MIN</sub> to T <sub>MAX</sub>			0.09		
On-Resistance Flatness	R <sub>FLAT</sub> (ON)	V+ = 2.7V, I <sub>COM</sub> _ = 100mA, V <sub>NO</sub> _ or V <sub>NC</sub> _ = 1V, 1.5V, 2V	+25°C		0.05	0.18	Ω	
(Note 5)			T <sub>MIN</sub> to T <sub>MAX</sub>			0.20		
NO_ or NC_ Off-Leakage INO (OFF),		V+ = 3.3V,	+25°C	-1		1	nA	
Current	INC_(OFF)	V <sub>COM</sub> = 0.3V, 3V, V <sub>NO</sub> or V <sub>NC</sub> = 3V, 0.3V	T <sub>MIN</sub> to T <sub>MAX</sub>	-5		5	IIA	
0011 011 1 0			+25°C	-1		1		
COM_ Off-Leakage Current	ICOM_(OFF)	$V_{COM}$ = 0.3V, 3V $V_{NO}$ or $V_{NC}$ = 3V, 0.3V or floating	T <sub>MIN</sub> to T <sub>MAX</sub>	-5		5	nA	
		V+ = 3.3V, VCOM_ = 3V, 0.3V;	+25°C	-2		2		
COM_ On-Leakage Current	ICOM_(ON)	$V_{NO}$ or $V_{NC}$ = 3V, 0.3V or floating	T <sub>MIN</sub> to T <sub>MAX</sub>	-10		10	nA 	

## **ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)**

 $(V+=+2.7V \text{ to } +3.6V, V_{IH}=+1.4V, V_{IL}=+0.5V, T_A=T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise specified. Typical values are at } V+=+3.0V, T_A=+25^{\circ}C.)$  (Notes 2, 3)

PARAMETER	RAMETER SYMBOL CONDITIONS		TA	MIN	TYP	MAX	UNITS	
SWITCH DYNAMIC CHARACTERISTICS								
Turn-On Time	ton	$V_{NO_{-}}, V_{NC_{-}} = 1.5V,$ $R_{L} = 50\Omega, C_{L} = 35pF,$	+25°C		18	24	ns	
ram on nine	UN	Figure 1	T <sub>MIN</sub> to T <sub>MAX</sub>			28	113	
Turn-Off Time	torr	$V_{NO_{-}}, V_{NC_{-}} = 1.5V,$ $R_{L} = 50\Omega, C_{L} = 35pF,$	+25°C		12	16	ns	
Turr-On Time	toff	Figure 1	T <sub>MIN</sub> to T <sub>MAX</sub>			18	115	
Prock Potoro Mako (Noto 6)	toou	$V_{NO}$ , $V_{NC}$ = 1.5V, $R_L$ = 50 $\Omega$ , $C_L$ = 35pF,	+25°C		6		20	
Break-Before-Make (Note 6)	<sup>†</sup> BBM	Figure 1 (MAX4743)	T <sub>MIN</sub> to T <sub>MAX</sub>	1			ns	
Charge Injection	Q	V <sub>GEN</sub> = 0, R <sub>GEN</sub> = 0, C <sub>L</sub> = 1.0nF, Figure 3	+25°C		28		рС	
NO_ or NC_ Off- Capacitance	Coff	f = 1MHz, Figure 4	+25°C		32		pF	
COM_ Off-Capacitance	C <sub>COM_(OFF)</sub>	f = 1MHz, Figure 4	+25°C		32		рF	
COM_ On-Capacitance	C <sub>COM</sub> (ON)	f = 1MHz, Figure 4	+25°C		44		pF	
-3dB On-Channel Bandwidth	BW	Signal = 0, $R_{IN} = R_{OUT} = 50\Omega$ , $C_L = 5pF$ , Figure 2			100		MHz	
Off-Isolation (Note 7)	V <sub>ISO</sub>	$f = 1MHz$ , $V_{COM} = 1V_{RMS}$ , $R_L = 50\Omega$ , $C_L = 5pF$ , Figure 2	+25°C		-55		dB	
Crosstalk (Note 8)		$f = 1MHz$ , $V_{COM} = 1V_{RMS}$ , $R_L = 50\Omega$ , $C_L = 5pF$ , Figure 2	+25°C		-110		dB	
Total Harmonic Distortion	THD	$f = 20$ Hz to $20$ kHz, $V_{COM} = 2$ Vp-p, $R_L = 32\Omega$	+25°C		0.02		%	
LOGIC INPUT								
Input Logic High	VIH			1.4			V	
Input Logic Low	V <sub>IL</sub>					0.5	V	
Input Leakage Current	I <sub>IN</sub>	$V_{IN} = 0$ or $V+$		-1	0.005	1	μΑ	
POWER SUPPLY								
Power-Supply Range	V+			1.6		3.6	V	
Positive Supply Current	l+	V+ = 3.6V, V <sub>IN</sub> _ = 0 or V+, all channels on or off	+25°C			0.2	μА	

## **ELECTRICAL CHARACTERISTICS—Single +1.8V Supply**

 $(V+=+1.8V,\,V_{IH}=+1.0V,\,V_{IL}=0.4V,\,T_{A}=T_{MIN}\,to\,T_{MAX},\,unless\,otherwise\,specified.\,Typical\,values\,are\,at\,T_{A}=+25^{\circ}C.)\,(Notes\,2,\,3)$ 

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS	
ANALOG SWITCH								
Analog Signal Range	VCOM_, VNO_, VNC_			0		V+	V	
On-Resistance	Ron	I <sub>COM</sub> _ = 10mA,	+25°C		1.3	2.5	Ω	
		$V_{NO}$ or $V_{NC}$ = 0.9V	T <sub>MIN</sub> to T <sub>MAX</sub>			5		
NO_ or NC_ Off-Leakage	INO_(OFF),	$V_{COM} = 0.3V, 1.5V;$ $V_{NO}$ or $V_{NC} = 1.5V,$	+25°C	-1		1	nA	
Current	INC_(OFF)	0.3V	T <sub>MIN</sub> to T <sub>MAX</sub>	-5		5	117 (	
COM Off Lackage Current	1	V <sub>COM</sub> _ = 0.3V, 1.5V;	+25°C	-1		1	A	
COM_ Off-Leakage Current	ICOM_(OFF)	$V_{NO}$ or $V_{NC}$ = 1.5V, 0.3V	T <sub>MIN</sub> to T <sub>MAX</sub>	-5		5	- nA	
0011 0 1 1 0		V <sub>COM</sub> = 0.3V, 1.5V,	+25°C	-2		2		
COM_ On-Leakage Current	ICOM_(ON)	$V_{NO}$ or $V_{NC}$ = 0.3V, 1.5V, or floating	T <sub>MIN</sub> to T <sub>MAX</sub>	-10		10	nA	
SWITCH DYNAMIC CHARACTE	RISTICS							
T 0 T		V <sub>NO</sub> _, V <sub>NC</sub> _ = 1.5V,	+25°C		25	35		
Turn-On Time	ton	$R_L = 50\Omega$ , $C_L = 35pF$ , Figure 1	T <sub>MIN</sub> to T <sub>MAX</sub>			40	ns	
- 0//-		V <sub>NO</sub> _, V <sub>NC</sub> _ = 1.5V,	+25°C		16	25	ns	
Turn-Off Time	tOFF	$R_L = 50\Omega$ , $C_L = 35pF$ , Figure 1	T <sub>MIN</sub> to T <sub>MAX</sub>			30		
		V <sub>NO</sub> _, V <sub>NC</sub> _ = 1.5V,	+25°C		10		1	
Break-Before-Make (Note 6)	tBBM	$R_L = 50\Omega$ , $C_L = 35pF$ , Figure 1 (MAX4743)	T <sub>MIN</sub> to T <sub>MAX</sub>	1			ns	
Charge Injection	Q	$V_{GEN} = 0$ , $R_{GEN} = 0$ , $C_L = 1$ nF, Figure 2	+25°C		16		рС	
Off-Isolation (Note 7)	V <sub>ISO</sub>	$f = 1 MHz, V_{NO} = V_{NC}$ $= 1 V_{RMS}, R_L = 50\Omega,$ $C_L = 5pF, Figure 2$	$V_{RMS}$ , $R_L = 50\Omega$ , $+25^{\circ}C$ -50			dB		
Crosstalk (Note 8)		$f = 1 \text{MHz}, V_{\text{COM}} = 1 \text{V}_{\text{RMS}},$ $R_{\text{L}} = 50 \Omega,$ $C_{\text{L}} = 5 \text{pF}, \text{Figure 2}$	+25°C	-110		dB		

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### **ELECTRICAL CHARACTERISTICS—Single +1.8V Supply (continued)**

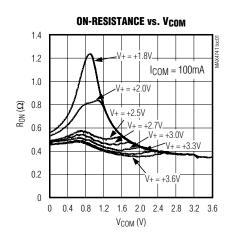
 $(V+=+1.8V, V_{IH}=+1.0V, V_{IL}=0.4V, T_A=T_{MIN}$  to  $T_{MAX}$ , unless otherwise specified. Typical values are at  $T_A=+25$ °C.) (Notes 2, 3)

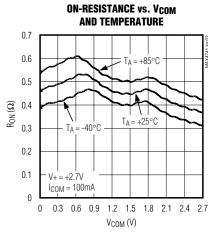
PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
LOGIC INPUT							
Input Logic High	VIH			1			V
Input Logic Low	VIL					0.4	V
Input Leakage Current	IIN	V <sub>IN</sub> _ = 0 or V+		-1		1	μΑ

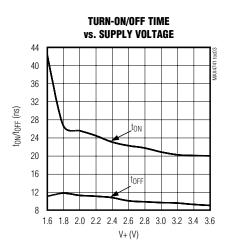
- **Note 2:** The algebraic convention, where the most negative value is a minimum and the most positive value is a maximum, is used in this data sheet.
- Note 3: SOT23 packaged parts are 100% tested at +25°C. Limits across the full temperature range are guaranteed by design and correlation. μMAX packaged parts -40°C specifications are guaranteed by design.
- Note 4:  $\Delta R_{ON} = R_{ON(MAX)} R_{ON(MIN)}$ .
- **Note 5:** Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured over the specified analog signal ranges.
- Note 6: Guaranteed by design.
- **Note 7:** Off-Isolation =  $20\log_{10}(V_{COM}/V_{NO})$ ,  $V_{COM}$  = output,  $V_{NO}$  = input to off switch.
- Note 8: Between two switches.

## Typical Operating Characteristics

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$ 

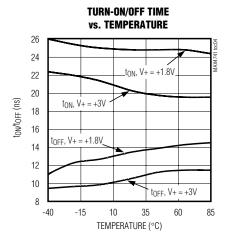


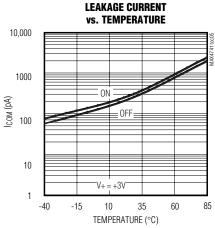


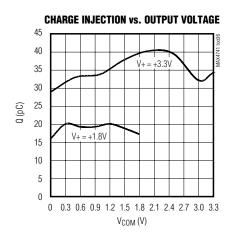


### Typical Operating Characteristics (continued)

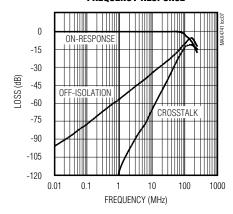
 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$ 



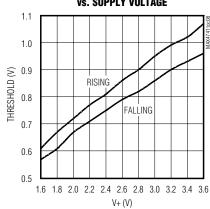




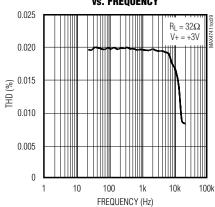
#### FREQUENCY RESPONSE



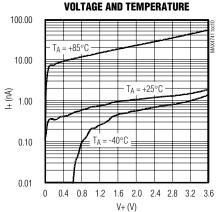




## TOTAL HARMONIC DISTORTION vs. Frequency



## SUPPLY CURRENT vs. SUPPLY



### **Pin Description**

		F	PIN				
MAX	MAX4741		(4742	MAX4743		NAME	FUNCTION
μМΑΧ	SOT23-8	μ <b>МАХ</b>	SOT23-8	μ <b>МАХ</b>	SOT23-8		
1	8	_	_	1	8	NO1	Analog Switch 1 Normally Open
_	_	1	8	_	_	NC1	Analog Switch 1 Normally Closed
2	7	2	7	2	7	COM1	Analog Switch 1 Common
3	6	3	6	3	6	IN2	Logic Control Input Switch 2
4	5	4	5	4	5	GND	Ground
5	3	_	_	_	_	NO2	Analog Switch 2 Normally Open
_	_	5	3	5	3	NC2	Analog Switch 2 Normally Closed
6	4	6	4	6	4	COM2	Analog Switch 2 Common
7	1	7	1	7	1	IN1	Logic Control Input Switch 1
8	2	8	2	8	2	V+	Positive Supply Voltage

### Detailed Description

The MAX4741/MAX4742/MAX4743 are low  $0.8\Omega$  max (at V+ = +3V) on-resistance, low-voltage, dual analog switches that operate from a +1.6V to +3.6V single supply. CMOS switch construction allows switching analog signals that are within the supply voltage range (GND to V+).

When powered from a +3V supply, the 0.8  $\!\Omega$  max RoN allows high continuous currents to be switched in a variety of applications.

### **Applications Information**

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, followed by NO\_, NC\_, or COM\_.

Although it is not required, power-supply bypassing improves noise margin and prevents switching noise propagation from the V+ supply to other components. A  $0.1\mu F$  capacitor, connected from V+ to GND, is adequate for most applications.

#### **Logic Inputs**

The MAX4741/MAX4742/MAX4743 logic inputs can be driven up to +3.6V regardless of the supply voltage. For example, with a +1.8V supply, IN\_ may be driven low to GND and high to +3.6V. Driving IN\_ rail-to-rail minimizes power consumption.

### **Analog Signal Levels**

Analog signals that range over the entire supply voltage (V+ to GND) can be passed with very little change in onresistance (see *Typical Operating Characteristics*). The switches are bidirectional, so the NO\_, NC\_, and COM\_ pins can be used as either inputs or outputs.

#### Layout

High-speed switches require proper layout and design procedures for optimum performance. Reduce stray inductance and capacitance by keeping traces short and wide. Ensure that bypass capacitors are as close to the device as possible. Use large ground planes where possible.

## **Test Circuits/Timing Diagrams**

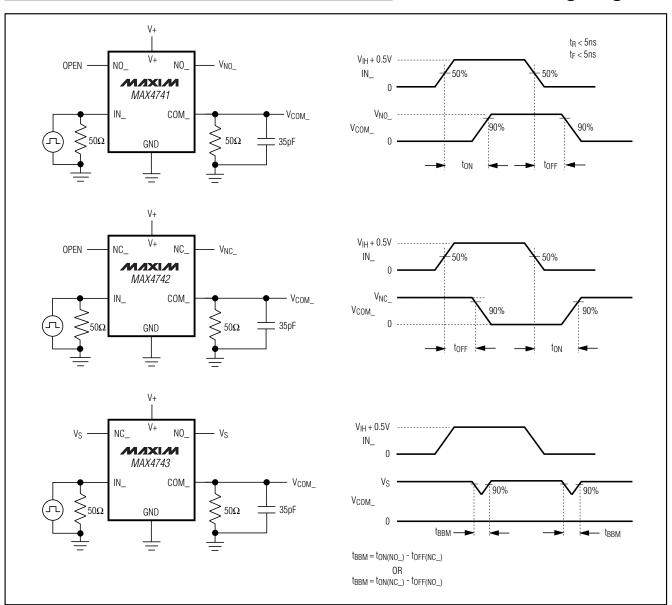


Figure 1. Switching Times

## Test Circuits/Timing Diagrams (continued)

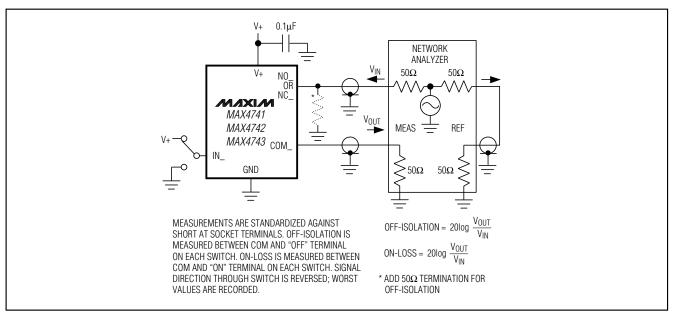


Figure 2. Off-Isolation, On-Loss, and Crosstalk

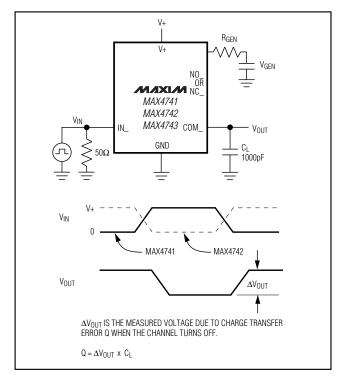


Figure 3. Charge Injection

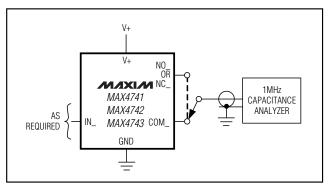
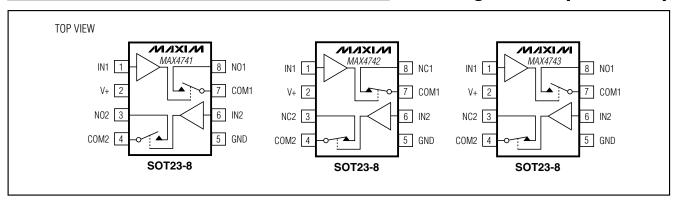


Figure 4. NO\_, NC\_, and COM\_ Capacitance

## Pin Configurations (continued)

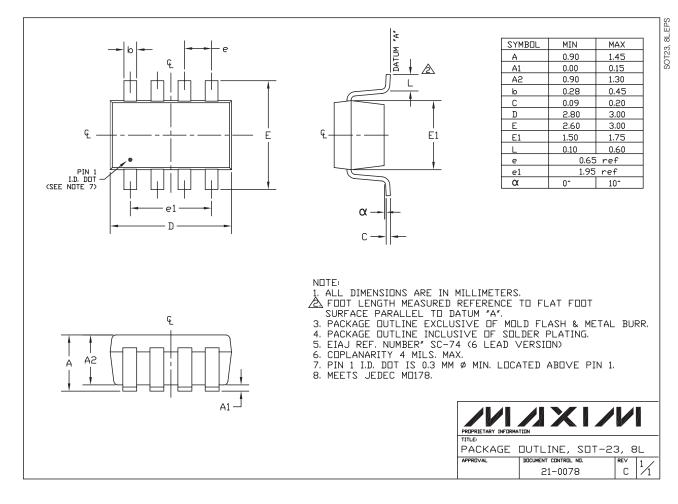


## **Chip Information**

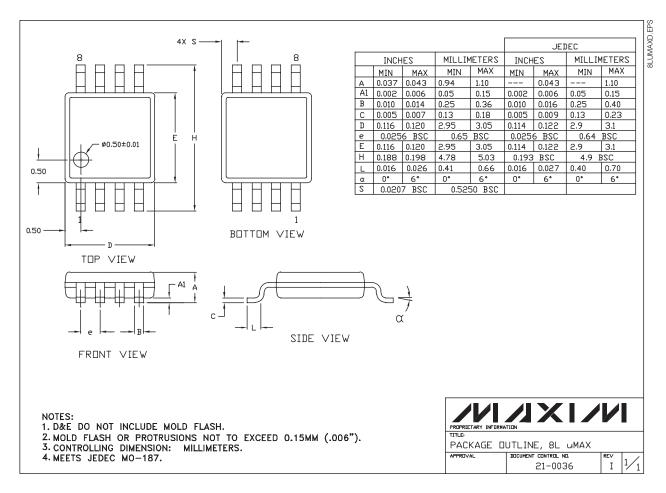
TRANSISTOR COUNT = 121 PROCESS = CMOS

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## Package Information



## Package Information (continued)



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